

**H11A1X, H11A2X, H11A3X, H11A4X, H11A5X  
H11A1, H11A2, H11A3, H11A4, H11A5**



**OPTICALLY COUPLED  
ISOLATOR  
PHOTOTRANSISTOR OUTPUT**

**APPROVALS**

- UL recognised, File No. E91231
- 'X' SPECIFICATION APPROVALS
- VDE 0884 in 3 available lead forms : -
  - STD
  - G form
  - SMD approved to CECC 00802
- Certified to EN60950 by the following Test Bodies :-
  - Nemko - Certificate No. P96101299
  - Fimko - Registration No. 190469-01..22
  - Semko - Reference No. 9620076 01
  - Demko - Reference No. 305567

**DESCRIPTION**

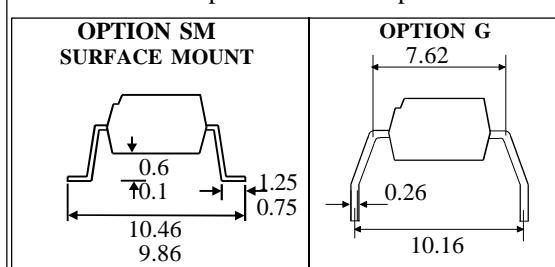
The H11A series of optically coupled isolators consist of infrared light emitting diode and NPN silicon photo transistor in a standard 6 pin dual in line plastic package.

**FEATURES**

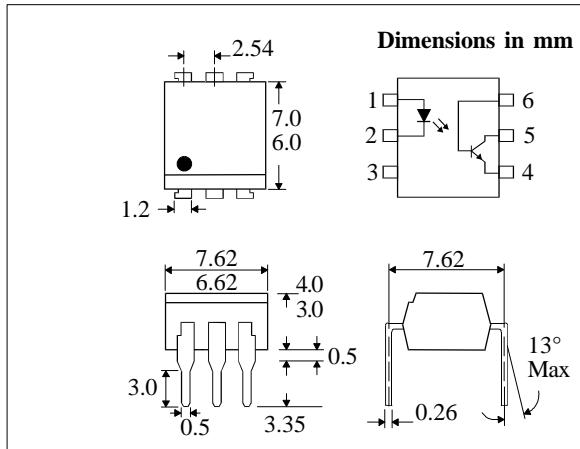
- Options :-
  - 10mm lead spread - add G after part no.
  - Surface mount - add SM after part no.
  - Tape&reel - add SMT&R after part no.
- High Isolation Voltage ( $5.3\text{ kV}_{\text{RMS}}$ ,  $7.5\text{ kV}_{\text{PK}}$ )
- All electrical parameters 100% tested
- Custom electrical selections available

**APPLICATIONS**

- DC motor controllers
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances



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**ABSOLUTE MAXIMUM RATINGS  
(25°C unless otherwise specified)**

Storage Temperature \_\_\_\_\_ -55°C to + 150°C  
Operating Temperature \_\_\_\_\_ -55°C to + 100°C  
Lead Soldering Temperature  
(1/16 inch (1.6mm) from case for 10 secs) 260°C

**INPUT DIODE**

Forward Current \_\_\_\_\_ 60mA  
Reverse Voltage \_\_\_\_\_ 6V  
Power Dissipation \_\_\_\_\_ 105mW

**OUTPUT TRANSISTOR**

Collector-emitter Voltage  $\text{BV}_{\text{CEO}}$  \_\_\_\_\_ 30V  
Collector-base Voltage  $\text{BV}_{\text{CBO}}$  \_\_\_\_\_ 70V  
Emitter-collector Voltage  $\text{BV}_{\text{ECO}}$  \_\_\_\_\_ 6V  
Power Dissipation \_\_\_\_\_ 160mW

**POWER DISSIPATION**

Total Power Dissipation \_\_\_\_\_ 200mW  
(derate linearly 2.67mW/°C above 25°C)

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**ELECTRICAL CHARACTERISTICS (  $T_A = 25^\circ\text{C}$  Unless otherwise noted )**

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage ( $V_F$ ) Reverse Voltage ( $V_R$ ) Reverse Current ( $I_R$ )	6	1.2	1.5	V V $\mu\text{A}$	$I_F = 10\text{mA}$ $I_R = 10\mu\text{A}$ $V_R = 6\text{V}$
Output	Collector-emitter Breakdown ( $BV_{CEO}$ ) ( note 2 ) Collector-base Breakdown ( $BV_{CBO}$ ) Emitter-collector Breakdown ( $BV_{ECO}$ ) Collector-emitter Dark Current ( $I_{CEO}$ ) Collector-base Dark Current ( $I_{CBO}$ )	30 70 6 50 20			V V V $\text{nA}$ $\text{nA}$	$I_C = 1\text{mA}$ $I_C = 100\mu\text{A}$ $I_E = 100\mu\text{A}$ $V_{CE} = 10\text{V}$ $V_{CE} = 10\text{V}$
Coupled	Current Transfer Ratio (CTR) H11A1 H11A2 H11A3 H11A4 H11A5 Collector-emitter Saturation Voltage $V_{CE(SAT)}$ Input to Output Isolation Voltage $V_{ISO}$ Input-output Isolation Resistance $R_{ISO}$ Output Rise Time $t_r$ Output Fall Time $t_f$	50 20 20 10 30 5300 7500 $5 \times 10^{10}$		0.4	% % % % % V $V_{RMS}$ $V_{PK}$ $\Omega$ $\mu\text{s}$ $\mu\text{s}$	10mA $I_F$ , 10V $V_{CE}$ 10mA $I_F$ , 0.5mA $I_C$ See note 1 See note 1 $V_{IO} = 500\text{V}$ (note 1) $V_{CC} = 10\text{V}$ , $I_C = 2\text{mA}$ $R_L = 100\Omega$ fig 1

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

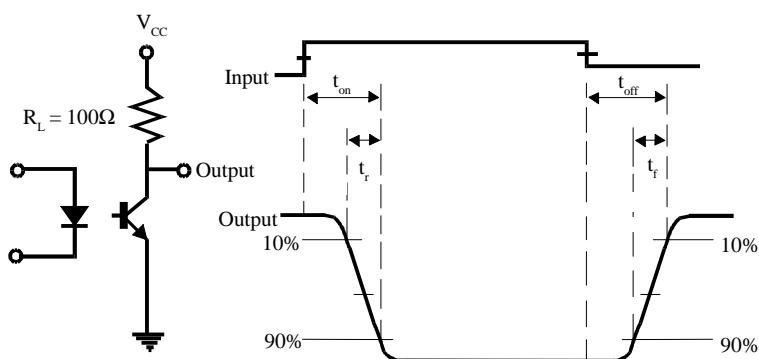


FIG 1

